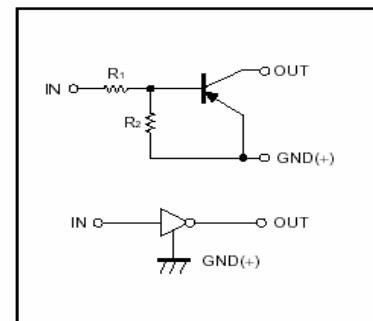


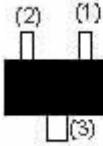
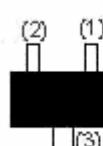
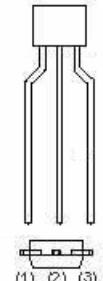
Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



PIN CONNECTIONS AND MARKING

DTA123YE  SOT-523 Addreviated symbol: 52	DTA123YUA  SOT-323 Addreviated symbol: 52
DTA123YKA  SOT-23-3L Addreviated symbol: 52	DTA123YCA  SOT-23 Addreviated symbol: 52
DTA123YSA  TO-92S	

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA123Y□)					Unit			
		E	UA	KA	CA	SA				
Supply voltage	V _{CC}	-50					V			
Input voltage	V _{IN}	-12~5					V			
Output current	I _O	-100					mA			
	I _{C(MAX)}	-100								
Power dissipation	P _d	150	200			300	mW			
Junction temperature	T _j	150					°C			
Storage temperature	T _{stg}	-55~150					°C			

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			-0.3	V	V _{CC} =-5V , I _O =-100μA
	V _{I(on)}	-3				V _O =-0.3V , I _O =-20 mA
Output voltage	V _{O(on)}			-0.3	V	I _O /I _I =-10mA/-0.5mA
Input current	I _I			-3.8	mA	V _I =-5V
Output current	I _{O(off)}			-0.5	μA	V _{CC} =-50V , V _I =0
DC current gain	G _I	33				V _O =-5V , I _O =-10mA
Input resistance	R _I	1.54	2.2	2.86	KΩ	
Resistance ratio	R ₂ /R ₁	3.6	4.5	5.5		
Transition frequency	f _T		250		MHz	V _{CE} =-10V , I _E =5mA,f=100MHz

Typical Characteristics

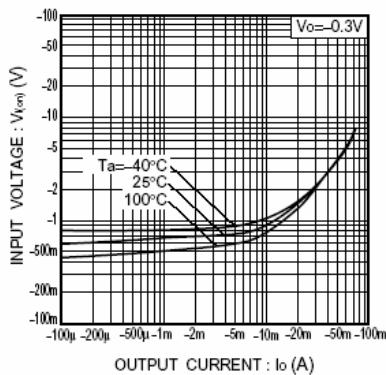
•Electrical characteristic curves


Fig.1 Input voltage vs. output current
(ON characteristics)

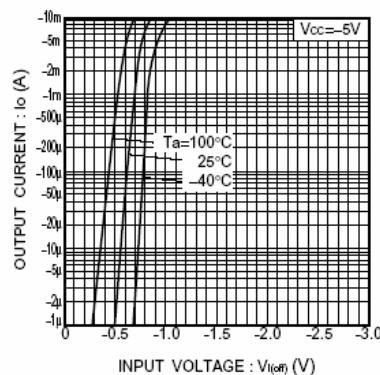


Fig.2 Output current vs. input voltage
(OFF characteristics)

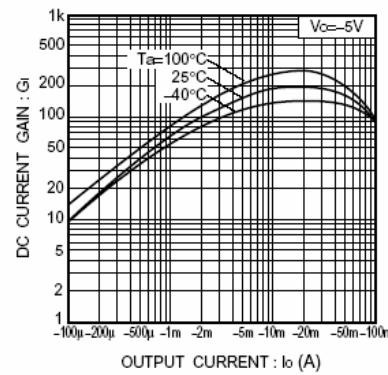


Fig.3 DC current gain vs. output current

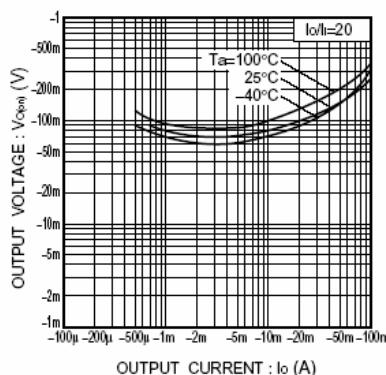


Fig.4 Output voltage vs. output current